



40V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	Rds(ON) Max	I _D Max T _C = +25°C		
40V	12.3mΩ @ V _{GS} = 10V	46.2A		
400	$17.5 \text{m}\Omega$ @ V _{GS} = 4.5V	38.7A		

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power Management Functions
- DC-DC Converters

Features and Benefits

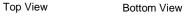
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching, Test in Production— Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMTH4008LPDWQ</u>)

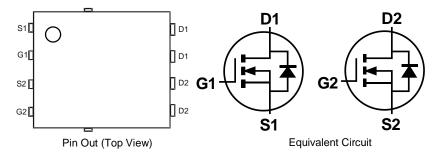
Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)

PowerDI5060-8/SWP (Type UXD)







Ordering Information (Note 4)

ſ	Part Number	Case	Packaging	
	DMTH4008LPDW-13	PowerDI5060-8/SWP (Type UXD)	2,500/Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking
TH4008LDW = Product Type Marking Code
YYWW or YYWW = Date Code Marking
YY or YY = Year (ex: 20 = 2020)
WW = Week (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	40	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current (Note 5)	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	lo	10.0 7.1	А
Continuous Drain Current (Note 6) $ T_C = +25^{\circ}C $ $ T_C = +100^{\circ}C $		ID	46.2 32.7	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	184	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	43.7	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 19	I _{SM}	184	Α	
Avalanche Current, L = 0.1mH		las	23.1	Α
Avalanche Energy, L = 0.1mH		Eas	26.6	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5) $T_A = +25^{\circ}C$		PD	2.67	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	56.6	°C/W	
Total Power Dissipation (Note 6)	PD	39.4	W	
Thermal Resistance, Junction to Case (Note 6)	R ₀ JC	3.8	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

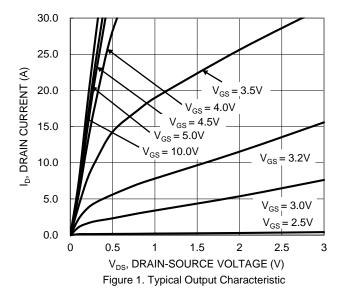
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

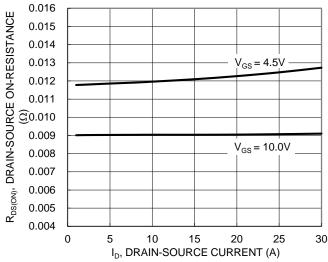
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		40	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current		_	_	1	μΑ	V _{DS} = 32V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.2	1.88	2.3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	Descou	_	9.5	12.3	mΩ	VGS = 10V, ID = 20A	
Static Drain-Source On-Resistance	RDS(ON)	_	11.9	17.5	mΩ	Vgs = 4.5V, ID = 10A	
Diode Forward Voltage	V _{SD}	_	0.9	1.2	V	V _{GS} = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)	•			•	•		
Input Capacitance	Ciss	_	881	_	pF	V _{DS} = 20V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	496	_	pF		
Reverse Transfer Capacitance	Crss		19.5	_	pF		
Gate Resistance	Rg		2.06	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	12.3	_	nC		
Total Gate Charge (V _{GS} = 4.5V)			5.8	_	nC	1, 20,4 1 20,4	
Gate-Source Charge	Qgs	_	2.6	_	nC	$V_{DS} = 20V, I_{D} = 20A$	
Gate-Drain Charge	Qgd	_	1.6	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.82	_	ns		
Turn-On Rise Time	t _R	_	4.76	_	ns	V _{DD} = 20V, V _{GS} = 10V,	
Turn-Off Delay Time	tD(OFF)	-	12.6	_	ns	$R_g = 3\Omega$, $I_D = 20A$	
Turn-Off Fall Time	tF	_	4.83	_	ns		
Body Diode Reverse Recovery Time	trr	_	31.9	_	ns	004 4744 40047	
Body Diode Reverse Recovery Charge	Q _{RR}	_	25.0	_	nC	$I_F = 20A$, di/dt = 100A/ μ s	

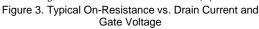
5. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate.

Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.









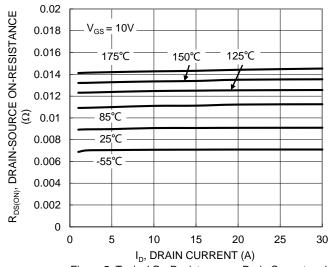
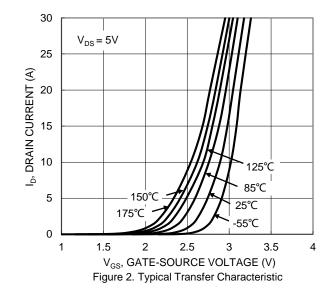
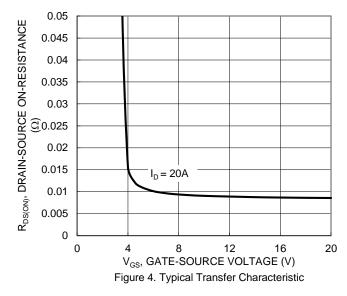


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





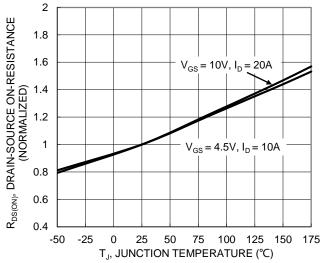


Figure 6. On-Resistance Variation with Temperature





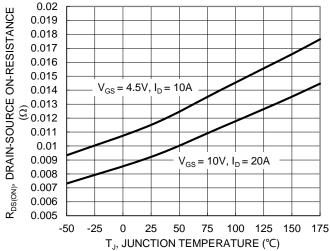
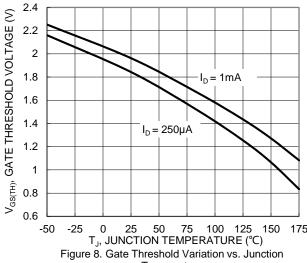


Figure 7. On-Resistance Variation with Temperature



Temperature

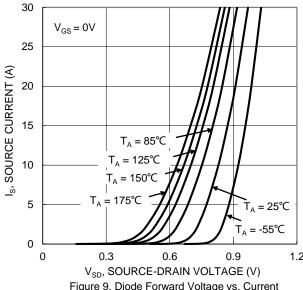
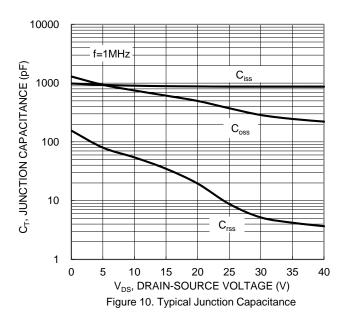


Figure 9. Diode Forward Voltage vs. Current



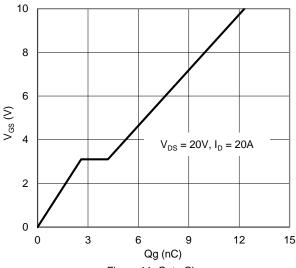
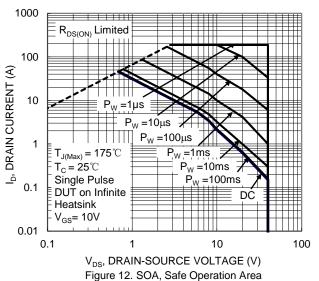


Figure 11. Gate Charge





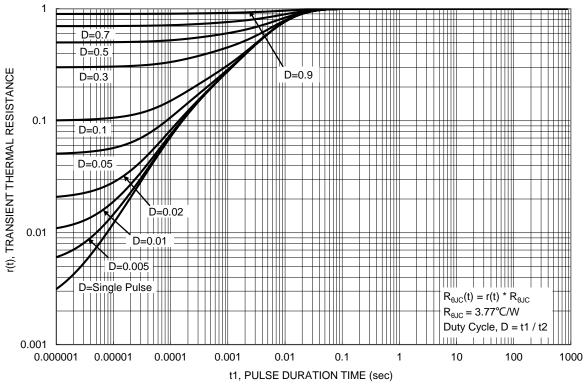


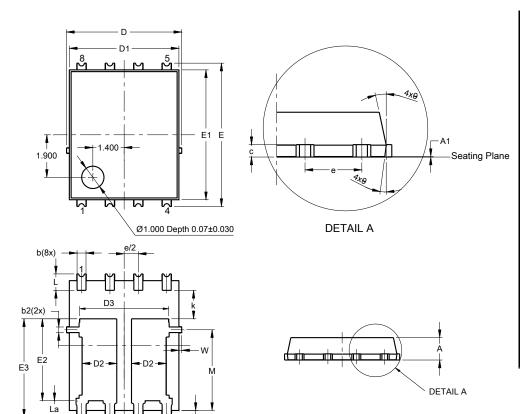
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UXD)

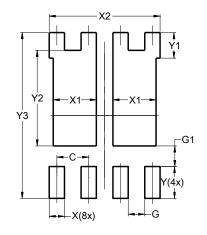


PowerDI5060-8/SWP						
	(Type UXD)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	C).25REF				
С	0.230	0.330	0.277			
D		.15 BS0				
D1	4.70	5.10	4.90			
D2	1.46	1.66	1.55			
D3	3.78	4.18	3.98			
Е	6.40 BSC					
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1	.27BSC)			
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
М	3.205	4.005	3.605			
W	0.025	0.225	0.125			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UXD)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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